Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Ceramic	
Overall Length:	
Between 0.150 inche	es and 0.180 inches
Terminal Length:	
1.500 inches	
Overall Diameter:	
Between 0.335 inche	es and 0.370 inches
Joint Electronic De	evice Engineering Council/jedec/case Outline Designation:
То-77	
Component Name	And Quantity:
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Dia	ameter:
0.200 inches	
Features Provided:	:
Hermetically sealed	case
Semiconductor Ma	iterial:
Silicon all transistor	
Voltage Rating In V	/olts Per Characteristic:
45.0 breakdown vol	ltage, collector-to-emitter, base open all semiconductor and 6.0 emitter to base voltage, static, collector open a
semiconductor	
Current Rating Per	Characteristic:
2.00 milliamperes so	ource cutoff current all semiconductor and 10.00 microamperes source cutoff current blank all semiconductor
Power Rating Per C	Characteristic:
400.0 milliwatts large	e-signal input power, common-emitter preset all semiconductor
Special Features:	
All transistor junctior	n pattern arrangement: npn
Terminal Type And	I Quantity:
6 uninsulated wire le	ead
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	